imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







Features

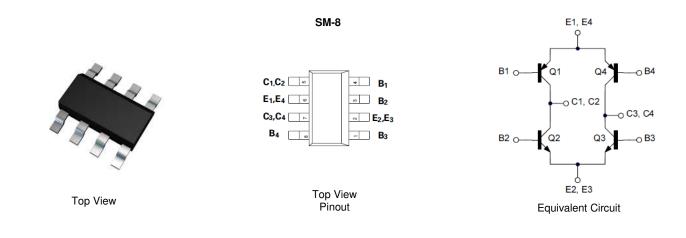
- BJT H-Bridge
- 2 x NPN + 2 x PNP
- I_c = 2.5A Continuous Collector Current
- NPN Transistor
 - BV_{CEO} > 20V
 - Low Saturation Voltage V_{CE(sat)} < 150mV @ 1A
 - PNP Transistor
 - BV_{CEO} > -20V
 - Low Saturation Voltage V_{CE(sat)} < -200mV @ -1A
 - Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SM-8 (8 LEAD SOT223)
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0

20V BIPOLAR TRANSISTOR H-BRIDGE IN SM-8

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.117 grams (Approximate)



Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZHB6718TA	ZHB6718	7	12	1,000

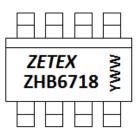
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



ZHB6718 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	NPN	PNP	Unit
Collector-Base Voltage	V _{CBO}	20	-20	V
Collector-Emitter Voltage	V _{CEO}	20	-20	V
Emitter-Base Voltage	V _{EBO}	7	-7	V
Continuous Collector Current	Ic	2.5	-2.5	A
Peak Pulse Current (Note 5)	I _{CM}	6	-6	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit		
Collector Bower Dissipation	(Note 5)	р	1.25	W	
Collector Power Dissipation	(Note 6)	PD	2		
Thermal Decistores Innetion to Ambient	(Note 5)	D	100	0 0 MU	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	62.5	°C/W	
Thermal Resistance, Junction to Lead		R _{θJL}	62	°C/W	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

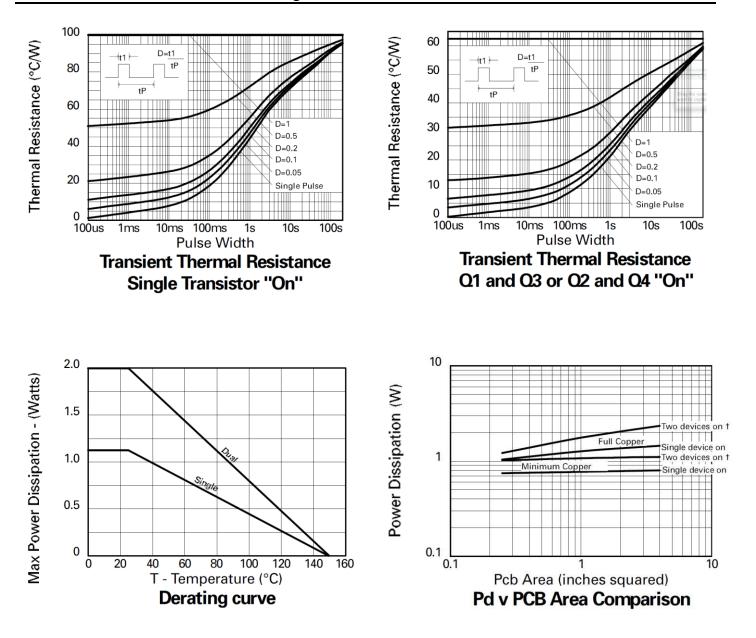
5. For a device with any single die active and mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state. Notes:

Same as Note (5), except both Q1/Q3 active or Q2/Q4 active and equally sharing power.
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



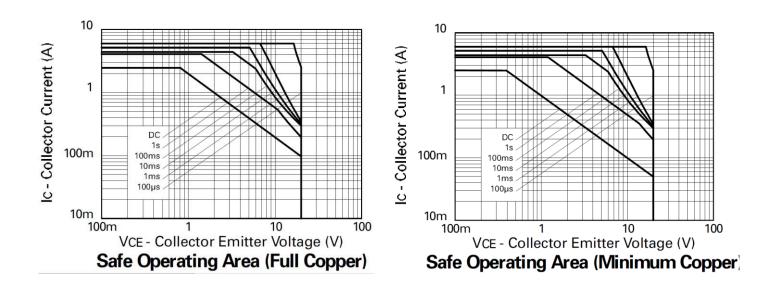
ZHB6718

Thermal Characteristics and Derating Information





Thermal Characteristics and Derating Information (continued)



Note: The Safe Operating Area (SOA) charts shown are a combination of the worst case secondary breakdown characteristics for the NPN/PNP pair, and the thermal curves demonstrating the power dissipation capability of the energized ZHB part (opposing NPN-PNP switched on) when mounted on a 50mm × 50mm FR4 PCB. The two cases show:

i) full copper present and

ii) with minimal copper present — this being defined as an SM-8 footprint with 1.5mm tracks to the edge of the PCB.

For example, on a 50mm × 50mm full copper PCB, the ZHB6718 will safely dissipate 2W under DC conditions, taking note of continuous current ratings and voltage limits. Higher powers can be tolerated for pulsed operation, while the shorter pulse widths (100µs and 1ms) being relevant for assessment of switching conditions.



NPN - Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

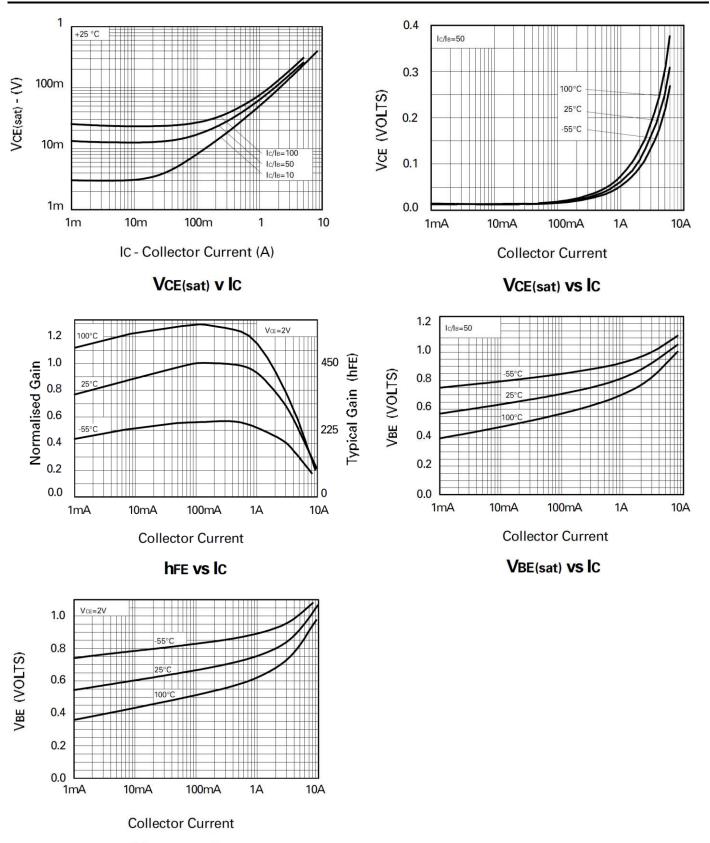
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	20	100	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	20	27	—	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	5	8.3	—	V	I _E = 100μA
Collector Cut Off Current	I _{CBO}	—	_	0.1	μΑ	V _{CB} = 16V
Emitter Cut Off Current	I _{EBO}	—	_	0.1	μΑ	$V_{EB} = 4V$
		200	400	—		$I_C = 10 \text{mA}, V_{CE} = 2 \text{V}$
DC Current Transfer Statia Datia (Nata 9)	h _{FE}	300	450	—		$I_{C} = 100 \text{mA}, V_{CE} = 2 \text{V}$
DC Current Transfer Static Ratio (Note 8)		200	360	—		$I_C = 2A, V_{CE} = 2V$
		_	180	—		$I_C = 6A, V_{CE} = 2V$
	V _{CE(sat)}	—	8	15	mV	$I_{\rm C} = 0.1 {\rm A}, I_{\rm B} = 10 {\rm mA}$
Collector-Emitter Saturation Voltage (Note 8)		_	70	150		$I_{\rm C} = 1$ A, $I_{\rm B} = 10$ mA
		_	130	200		$I_{C} = 2.5A, I_{B} = 50mA$
Base-Emitter Saturation Voltage (Note 8)	V _{BE(sat)}	—	0.89	1.0	V	$I_{C} = 2.5A, I_{B} = 50mA$
Base-Emitter Turn-on Voltage (Note 8)	V _{BE(on)}	—	0.79	—	V	$I_{C} = 2.5A, V_{CE} = 2V$
Transitional Frequency	f _T	100	140	—	MHz	$I_{C} = 50mA, V_{CE} = 10V, f = 100MHz$
Output Capacitance	C _{obo}	—	23	30	pF	V _{CB} = 10V, f = 1MHz
Switching Time	t _(ON)	—	170	—	nS	V _{CC} = 10V, I _C = 1A,
Switching Time	t _(Off)	—	400	—	nS	$I_{B1} = -I_{B2} = 10mA$

Note: 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



ZHB6718

NPN – Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



VBE(on) VS IC



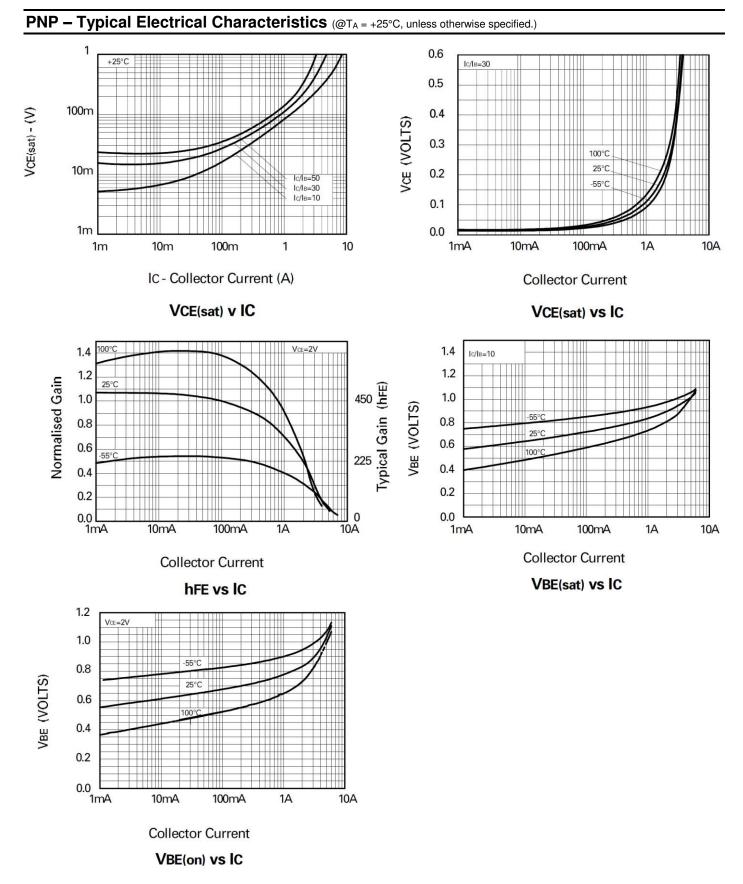
PNP - Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-20	-65	_	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-20	-55	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	-8.8	—	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	—	_	-0.1	μΑ	V _{CB} = -15V
Emitter Cutoff Current	I _{EBO}	—	_	-0.1	μΑ	$V_{EB} = -4V$
		300	475	—		$I_{C} = -10 \text{mA}, V_{CE} = -2 \text{V}$
		300	450	—		$I_{C} = -100 \text{mA}, V_{CE} = -2 \text{V}$
DC Current Transfer Static Ratio (Note 9)	h _{FE}	150	230	_		$I_{C} = -2A, V_{CE} = -2V$
		35	70	—		$I_{C} = -4A, V_{CE} = -2V$
		_	30	—		$I_{C} = -6A, V_{CE} = -2V$
	V _{CE(sat)}	—	-16	-40	mV	I _C = -100mA, I _B = -10mA
Collector-Emitter Saturation Voltage (Note 9)		_	-130	-200		I _C = -1A, I _B = -20mA
		_	-190	-260		I _C = -2.5A, I _B = -200mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	—	-0.98	-1.1	V	I _C = -2.5A, I _B = -200mA
Base-Emitter Turn-on Voltage (Note 9)	V _{BE(on)}	—	-0.85	_	V	$I_{C} = -2.5A, V_{CE} = -2V$
Transitional Frequency	f _T	150	180	_	MHz	$I_{C} = -50 \text{mA}, V_{CE} = -10 \text{V}, f = 100 \text{MHz}$
Output Capacitance	C _{obo}	—	21	30	pF	V _{CB} = -10V, f = 1MHz
Switching Time	t _(ON)		40		nS	V _{CC} = -10V, I _C = -1A,
	t(OFF)] —	670		nS	$I_{B1} = -I_{B2} = -20mA$

Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



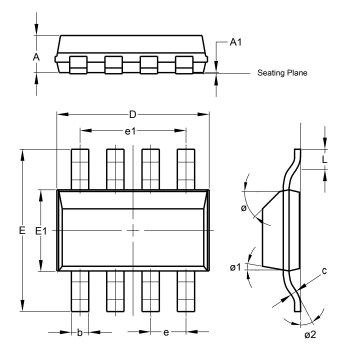
ZHB6718





Package Outline Dimensions

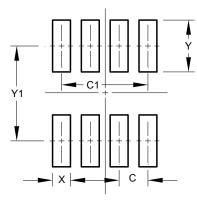
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SM-8					
Dim	Min Max Typ					
Α	-	1.70	1.60			
A1	0.02	0.10	0.04			
b	0.70	0.90	0.80			
С	0.24	0.32	0.28			
D	6.30 6.70 6.60					
е	1.53 REF					
e1		4.59 RE	F			
Е	6.70	7.30	7.00			
E1	3.30	3.70	3.50			
L	0.75	1.00	0.90			
Ø	45°					
Ø1		15°				
Ø2			10°			
All I	All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	1.52
C1	4.60
Х	0.95
Y	2.80
Y1	6.80

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com